

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX16244FT

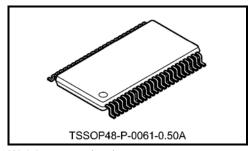
Low-Voltage 16-Bit Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX16244FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (2.5-V or 3.3-V) $V_{\rm CC}$ applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the $\overline{\rm OE}$ input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- Wide operating temperature range: Topr = -40 to 125 °C (Note 1)
- High-speed operation: $t_{pd} = 4.5 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: | I_{OH} |/I_{OL} = 24 mA (min) (V_{CC} = 3.0 V)
- Latch-up performance: -500 mA
- Package: TSSOP
- Power-down protection provided on all inputs and outputs

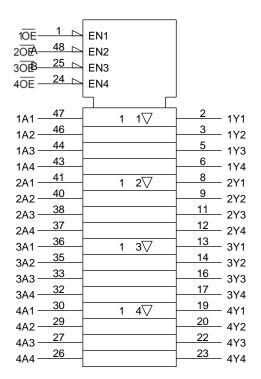
Note 1: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.



Pin Assignment (top view)

10E 48 2OE 2 1Y1 47 1A1 1Y2 3 1A2 46 GND 45 **GND** 1Y3 5 1A3 1Y4 6 43 1A4 7 Vcc Vcc 42 2Y1 8 2A1 2Y2 9 2A2 GND 10 **GND** 39 2A3 2Y3 11 38 2Y4 12 2A4 3Y1 13 3A1 3Y2 14 35 3A2 GND 15 34 GND 3Y3 16 33 3A3 3Y4 17 32 3A4 Vcc 18 31 Vcc 4Y1 19 4A1 30 4Y2 20 4A2 29 GND 21 28 **GND** 4Y3 22 4A3 4Y4 23 4A4 26 4OE 24 25 3OE

IEC Logic Symbol





Truth Table

Inputs		Outputs		
1 OE 1A1-1A4		1Y1-1Y4		
L	L	L		
L	Н	Н		
Н	Х	Z		

Inputs		Outputs
2 OE 2A1-2A4		2Y1-2Y4
L	L	L
L	Н	Н
Н	Х	Z

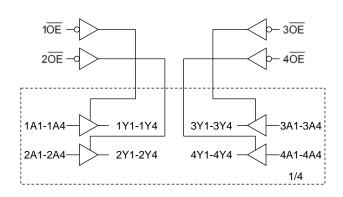
Inputs		Outputs
3OE 3A1-3A4		3Y1-3Y4
L	L	L
L	Н	Н
Н	Х	Z

Inputs		Outputs		
4OE 4A1-4A4		4Y1-4Y4		
L	L	L		
L	Н	Н		
Н	X	Z		

X: Don't care

Z: High impedance

System Diagram



2020-01-31



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	Vcc	-0.5 to 6.0	V	
Input voltage	VIN	-0.5 to 7.0	V	
		-0.5 to 7.0 (Note 1)	V	
Output voltage	Vout	-0.5 to V_{CC} + 0.5 (Note 2)		
Input diode current	lıĸ	-50	mA	
Output diode current	lok	±50 (Note 3)	mA	
DC output current	lout	±50	mA	
Power dissipation	PD	400 (Note 4)	mW	
DC V _{CC} / ground current per supply pin	ICC/ IGND	±100	mA	
Storage temperature	T _{stg}	-65 to 150	°C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state

Note 2: High or low state. IOUT absolute maximum rating must be observed.

Note 3: VOUT < GND, VOUT > VCC

Note 4: 400 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -6.25 mW/°C shall be applied until 150 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Dower aupply voltage	Vac	2.0 to 3.6	V
Power supply voltage	Vcc	1.5 to 3.6 (Note 1)	V
Input voltage	VIN	0 to 5.5	V
Output voltage	Vout	0 to 5.5 (Note 2)	V
Output voltage	VOU1	0 to V _{CC} (Note 3)	V
		±24 (Note 4)	
Output current	IOH/ IOL	±12 (Note 5)	mA
		±8 (Note 6)	
Operating temperature	Topr	-40 to 125 (Note 7)	°C
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 1: Data retention only

Note 2: Output in OFF state

Note 3: High or low state

Note 4: VCC = 3.0 to 3.6 V

Note 5: VCC = 2.7 to 3.0 V

Note 6: VCC = 2.3 to 2.7 V

Note 7: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.

Note 8: VIN = 0.8 to 2.0 V, VCC = 3.0 V



Electrical Characteristics

DC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics		Cumbal	Toot Con	dition		Min	Max	Unit
Characteri	Characteristics Symbol Test Condition		V _{CC} (V)	IVIIN	iviax	Unit		
H-level		\ /···			2.3 to 2.7	1.7	_	
Input voltage	VIH	_		2.7 to 3.6	2.0	_	V	
input voitage	L-level	VIL			2.3 to 2.7	_	0.7	V
	L-level	VIL	_		2.7 to 3.6	_	0.8	
			IOH = -100 μA	2.3 to 3.6	Vcc -0.2			
				IOH = -8 mA	2.3	1.8	_	
	H-level	Voн	VIN = VIH or VIL	IOH = -12 mA	2.7	2.2	_	V
Output voltage				IOH = -18 mA	3.0	2.4	_	
				IOH = -24 mA	3.0	2.2	_	
			VIN = VIH or VIL	$IOL = 100 \mu A$	2.3 to 3.6	_	0.2	
				IOL = 8 mA	2.3	_	0.6	
	L-level	VoL		I _{OL} = 12 mA	2.7	_	0.4	
				IOL = 16 mA	3.0	_	0.4	
				IOL = 24 mA	3.0	_	0.55	
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 5.5 V		2.3 to 3.6	_	±5.0	μА
3-state output off-state current		loz	VIN = VIH or VIL VOUT = 0 to 5.5 V		2.3 to 3.6	_	±5.0	μА
Power off leakage of	current	IOFF	VIN/VOUT = 5.5 V		0	_	10.0	μΑ
		Icc	V _{IN} = V _{CC} or GND		2.3 to 3.6		20.0	
Quiescent supply co	Quiescent supply current	100	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.3 to 3.6	_	±20.0	μΑ
		Δlcc	V _{IH} = V _{CC} - 0.6 V Per in	nput	2.3 to 3.6		500	



DC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 125 °C)

Characteristics Symbol Test Con-		Symbol	Tost Con	dition		Min	Max	Unit
		uition	V _{CC} (V)	IVIIII	IVIAX	Offic		
H-level		ViH				1.7	_	
Input voltage	VIH	_		2.7 to 3.6	2.0	_	V	
input voitage	L-level	VIL			2.3 to 2.7		0.7	V
	L-level	VIL	_		2.7 to 3.6		0.8	
				I _{OH} = -100 μA	2.3 to 3.6	Vcc -0.2		
				IOH = -8 mA	2.3	1.55		
	H-level	Voн	VIN = VIH or VIL	I _{OH} = -12 mA	2.7	2.0		V
Output voltage				$I_{OH} = -18 \text{ mA}$	3.0	2.2		
				IOH = -24 mA	3.0	1.9		
				IOL = 100 μA	2.3 to 3.6		0.2	
				IOL = 8 mA	2.3	_	0.9	
	L-level	VoL	VIN = VIH or VIL	I _{OL} = 12 mA	2.7	_	0.6	
				IOL = 16 mA	3.0		0.6	
				I _{OL} = 24 mA	3.0		0.8	
Input leakage currer	nt	liN	VIN = 0 to 5.5 V		2.3 to 3.6	_	±20.0	μΑ
3-state output off-state current		loz	VIN = VIH or VIL VOUT = 0 to 5.5 V			_	±20.0	μА
Power off leakage c	urrent	IOFF	VIN/VOUT = 5.5 V		0	_	40.0	μΑ
			VIN = VCC or GND		2.3 to 3.6	_	80.0	
Quiescent supply cu	Quiescent supply current	Icc	VIN/VOUT = 3.6 to 5.5 V		2.3 to 3.6	_	±80.0	μΑ
		Δlcc	VIH = VCC - 0.6 V Per in	nput	2.3 to 3.6	_	5000	

Note: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.



AC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Chaus et a vieti es	Currente el	Complete Took Condition				Mari	l lmit
Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
			2.5 ± 0.2	30	1.5	5.4	
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2	2.7	50	1.5	5.2	ns
	·pi iL		3.3 ± 0.3	50	1.5	4.5	
3-state output enable time			2.5 ± 0.2	30	1.5	7.2	
	t _P ZL t _P ZH	Figure 1, Figure 3	2.7	50	1.5	6.3	ns
			3.3 ± 0.3	50	1.5	5.5	
			2.5 ± 0.2	30	1.5	6.5	
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.7	50	1.5	5.7	ns
	φιιΖ		3.3 ± 0.3	50	1.5	5.4	
			2.5 ± 0.2	30	_	_	
Output to output skew	t _{osLH} t _{osHL}	(Note1)	2.7	50			ns
	LOSHL		3.3 ± 0.3	50	_	1.0	

Note1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

AC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 125 °C)

Characteristics	Cumbal	Symbol Test Condition			Min	Max	l loit
Characteristics	Symbol	rest Condition	Vcc (V)	C _L (pF)	IVIII	IVIAX	Unit
			2.5 ± 0.2	30	1.5	5.9	
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2	2.7	50	1.5	5.7	ns
	·pi iL		3.3 ± 0.3	50	1.5	4.9	
			2.5 ± 0.2	30	1.5	8.0	
3-state output enable time	t _{pZL} t _{pZH}	Figure 1, Figure 3	2.7	50	1.5	7.0	ns
			3.3 ± 0.3	50	1.5	6.1	
			2.5 ± 0.2	30	1.5	7.2	
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.7	50	1.5	6.3	ns
	φιιΖ		3.3 ± 0.3	50	1.5	6.0	
			2.5 ± 0.2	30	_	_	
Output to output skew	t _{osLH} t _{osHL}	(Note 1)	2.7	50	_	_	ns
	*USFIL		3.3 ± 0.3	50	_	1.0	

Note : Operating Range spec of Topr= -40 $^{\circ}$ C to 125 $^{\circ}$ C is applicable only for the products which manufactured after

January 2020.

Note1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)



Dynamic Switching Characteristics

(Unless otherwise specified, Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $R_L = 500~\Omega$)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum	Voi	Volp	V _{IH} = 2.5 V, V _{IL} = 0 V, C _L =30pF	2.5	0.6	V
dynamic	Vol	VOLP	V _{IH} = 3.3 V, V _{IL} = 0 V, C _L =50pF	3.3	0.8	V
Quiet output minimum	Vai	l\/o.v.d	V _{IH} = 2.5 V, V _{IL} = 0 V, C _L =30pF	2.5	0.6	V
dynamic	V _{OL}	Volv	V _{IH} = 3.3 V, V _{IL} = 0 V, C _L =50pF	3.3	0.8	V

Capacitive Characteristics (Unless otherwise specified, Ta = 25°C)

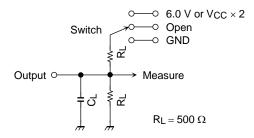
Characteristics	Symbol	Test Condition	V	/cc (V)	Тур.	Unit
Input capacitance	CIN	_		3.3	7	pF
Output capacitance	Cout	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (No.	ote1)	3.3	25	pF

Note1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/16 (per bit)

AC Test Circuit



Parameter	Switch		
tpLH, tpHL	Open		
tpLZ, tpZL	6.0 V VCC × 2	$@VCC = 3.3 \pm 0.3 \text{ V} \\ @VCC = 2.5 \pm 0.2 \text{ V} \\$	
t _{pHZ} , t _{pZH}	GND		

Figure 1



AC Waveform

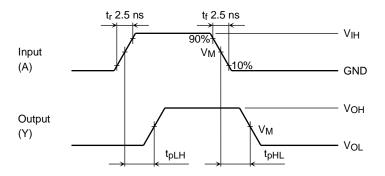


Figure 2 t_{pLH}, t_{pHL}

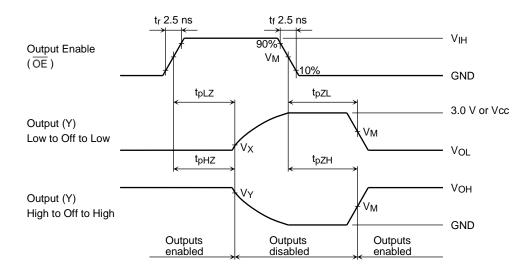


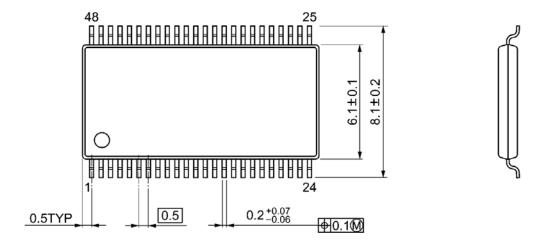
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

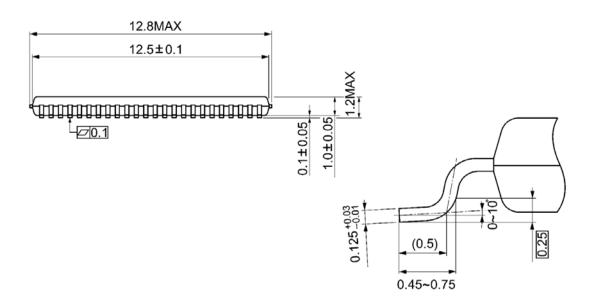
Commando a l	Vcc			
Symbol	$3.3\pm0.3~\textrm{V}$	2.7 V	$2.5\pm0.2~\textrm{V}$	
VIH	2.7 V	2.7 V	Vcc	
VM	1.5 V	1.5 V	V _{CC} /2	
Vx	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V	
VY	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 0.15 V	



Package Dimensions

TSSOP48-P-0061-0.50A Unit: mm





Weight: 0.25 g (typ.)



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